



DDTC (LO-R1) U

NPN PRE-BIASED 100 mA SURFACE MOUNT TRANSISTOR

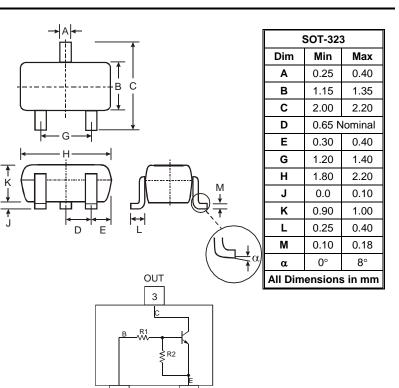
Features

- **Epitaxial Planar Die Construction**
- Complementary PNP Types Available (DDTA) .
- **Built-In Biasing Resistors**
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 & 4)

Mechanical Data

- Case: SOT-323 •
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	Type Code
DDTC122LU	0.22KΩ	10KΩ	N81
DDTC142JU	0.47KΩ	10KΩ	N82
DDTC122TU	0.22KΩ	OPEN	N83
DDTC142TU	0.47KΩ	OPEN	N84



Schematic and Pin Configuration

2

GND(0)

1

IN

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic		Symbol	Value	Unit	
Supply Voltage, (3) to (2)		Vcc	50	V	
Input Voltage, (1) to (2)	DDTC122LU DDTC142JU	V _{IN}	-5 to +6 -5 to +6	V	
Input Voltage, (2) to (1)	DDTC122TU DDTC142TU	V _{EBO (MAX)}	5	V	
Output Current	All	Ι _C	100	mA	
Power Dissipation	(Note 1)	Pd	200	mW	
Thermal Resistance, Junction to Ambient Air	(Note 1)	$R_{ hetaJA}$	625	°C/W	
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C	

Notes: Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf. 1.

2. No purposefully added lead.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants. 4.

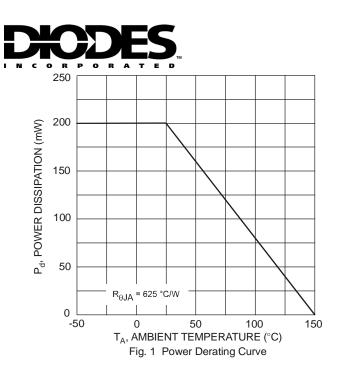


Electrical Characteristic	S @T _A = 25°C	unless otherwis	nless otherwise specified			R1, R2 Types				
Characteristic	Symbol	/mbol Min Typ			Unit	Test Condition				
Input Voltage	DDTC122LU DDTC142JU	V _{l(off)}	0.3 0.3	_	_	V	V _{CC} = 5V, I _O = 100μA			
	DDTC122LU DDTC142JU	V _{l(on)}		_	2.0 2.0	V	$V_0 = 0.3V, I_0 = 20mA$ $V_0 = 0.3V, I_0 = 20mA$			
Output Voltage		V _{O(on)}	_	—	0.3V	V	I _O /I _I = 5mA/0.25mA			
Input Current DDTC122LU DDTC142JU		II.	_	_	28 13	mA	$V_{I} = 5V$			
Output Current		I _{O(off)}	_	_	0.5	μA	$V_{CC} = 50V, V_I = 0V$			
DC Current Gain	Gı	56 56	_	_	_	V _O = 5V, I _O = 10mA				
Gain-Bandwidth Product*	f _T	_	200	_	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz				

* Transistor - For Reference Only

Electrical Characteristic	©T _A = 25°C	unless otherwis	d	R1-	,		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV _{CBO}	50			V	I _C = 50μA	
Collector-Emitter Breakdown Voltage	BV _{CEO}	40			V	I _C = 1mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	5			V	I _E = 50μA I _E = 50μA	
Collector Cutoff Current	I _{CBO}	_		0.5	μΑ	$V_{CB} = 50V$	
Emitter Cutoff Current DDTC122TU DDTC142TU		I _{EBO}			0.5 0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	_	0.3	V	$I_{\rm C} = 5$ mA, $I_{\rm B} = 0.25$ mA	
DC Current Transfer Ratio DDTC122TU DDTC142TU		h _{FE}	100 100	250 250	600 600	_	I _C = 1mA, V _{CE} = 5V
Gain-Bandwidth Product*	f _T	_	200	_	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz	

* Transistor - For Reference Only

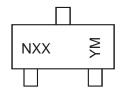


Ordering Information (Note 4 & 5)

	l.	
Device	Packaging	Shipping
DDTC122LU-7-F	SOT-323	3000/Tape & Reel
DDTC142JU-7-F	SOT-323	3000/Tape & Reel
DDTC122TU-7-F	SOT-323	3000/Tape & Reel
DDTC142TU-7-F	SOT-323	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



NXX = Product Type Marking Code, See Table on Page 1 YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key	1											
Year	2002	2003	2004	2005	200	6 20	07	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т	l	J	V	W	Х	Y	Z
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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MMUN2217LT1G FP101-TL-E RN1607(TE85L,F) DRC9A14E0L DTA124GKAT146 DTA144WETL DTA144WKAT146 DTC113EET1G DTC115TETL DTC115TKAT146 DTC124TETL DTC144ECA-TP DTC144VUAT106 MUN5241T1G BCR158WH6327XTSA1 NSBA114TDP6T5G NSBA143TF3T5G NSBA143ZF3T5G NSBC114EF3T5G NSBC114YF3T5G NSBC123TF3T5G NSBC143TF3T5G NSVMUN2212T1G NSVMUN5111DW1T3G NSVMUN5314DW1T3G NSVUMC2NT1G SMMUN2134LT1G SMUN2212T1G SMUN5235T1G SMUN5330DW1T1G SSVMUN5312DW1T2G 2SC3650-TD-E RN1303(TE85L,F) RN4605(TE85L,F) BCR135SH6327XT TTEPROTOTYPE79 UMC3NTR DTA113EET1G EMA2T2R EMH15T2R SDTA114YET1G SMMUN2111LT3G SMMUN2113LT1G SMMUN2114LT1G SMMUN2211LT3G SMUN2214T3G SMUN5113DW1T1G SMMUN5335DW1T1G NSBA114YF3T5G NSBC114TF3T5G